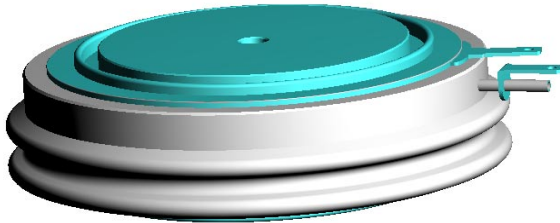


# GPTR1300

## PHASE CONTROLLED SCR



High reliability operation  
DC power supply  
AC drives

**VOLTAGE UP TO** **800 V**  
**AVERAGE CURRENT** **3000 A**  
**SURGE CURRENT** **30 kA**

### BLOCKING CHARACTERISTICS

Characteristic	Conditions	Value
VRRM	Repetitive peak reverse voltage	800 V
VRSM	Non-repetitive peak reverse voltage	900 V
VDRM	Repetitive peak off-state voltage	800 V
IDRM	Repetitive peak off-state current, max.	VDRM, single phase, half wave, T <sub>j</sub> = T <sub>jmax</sub>
IRRM	Repetitive peak reverse current, max.	VRRM, single phase, half wave, T <sub>j</sub> = T <sub>jmax</sub>

### ON-STATE CHARACTERISTICS

I <sub>T(AV)</sub>	Average on-state current	Sine wave, 180° conduction, Th = 55 °C	3000 A
I <sub>T(RMS)</sub>	R.M.S. on-state current	Sine wave, 180° conduction, Th = 55 °C	4712 A
I <sub>TSM</sub>	Surge on-state current	Non rep. half sine wave, 50 Hz, V <sub>R</sub> = 0 V, T <sub>j</sub> = T <sub>jmax</sub>	30 kA
I <sup>2</sup> t	I <sup>2</sup> t for fusing coordination		4500 kA <sup>2</sup> s
V <sub>T(TO)</sub>	Threshold voltage	T <sub>j</sub> = T <sub>jmax</sub>	1,0 V
r <sub>T</sub>	On-state slope resistance	T <sub>j</sub> = T <sub>jmax</sub>	0,116 mΩ
V <sub>TM</sub>	Peak on-state voltage, max	On-state current I <sub>T</sub> = 6300 A , T <sub>j</sub> = 25 °C	1,78 V
I <sub>H</sub>	Holding current, max	T <sub>j</sub> = 25 °C	300 mA
I <sub>L</sub>	Latching current, typ	T <sub>j</sub> = 25 °C	500 mA

### TRIGGERING CHARACTERISTICS

V <sub>GT</sub>	Gate trigger voltage	T <sub>j</sub> = 25 °C, V <sub>D</sub> = 5 V	3 V
I <sub>GT</sub>	Gate trigger current	T <sub>j</sub> = 25 °C, V <sub>D</sub> = 5 V	400 mA
V <sub>GD</sub>	Non-trigger voltage	V <sub>D</sub> = 67% VRRM, T <sub>j</sub> = T <sub>jmax</sub>	0,1 V
P <sub>GM</sub>	Peak gate power dissipation	Pulse width 0.5 ms	100 W
P <sub>G(AV)</sub>	Average gate power dissipation		5 W
I <sub>FGM</sub>	Peak gate current		30 A
V <sub>FGM</sub>	Peak gate voltage (forward)		12 V
V <sub>RGM</sub>	Peak gate voltage (reverse)		3 V

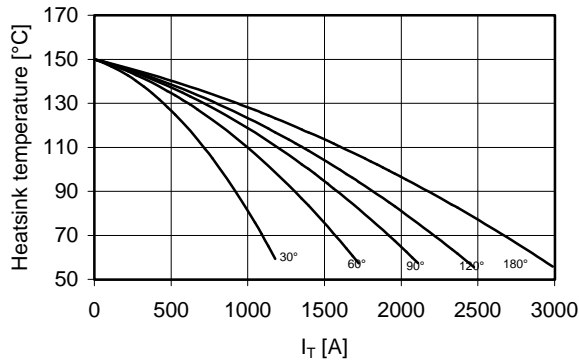
### SWITCHING CHARACTERISTICS

di/dt	Critical rate of rise of on-state current	T <sub>j</sub> = T <sub>jmax</sub>	200 A/μs
dV/dt	Critical rate of rise of off-state voltage	T <sub>j</sub> = T <sub>jmax</sub>	500 V/μs
t <sub>q</sub>	Turn-off time, typ	T <sub>j</sub> = T <sub>jmax</sub> , I <sub>T</sub> = 800 A, di/dt = -12.5 A/μs V <sub>R</sub> = 100 V, V <sub>D</sub> = 67% VDRM, dV/dt = 20 V/μs	400 μs

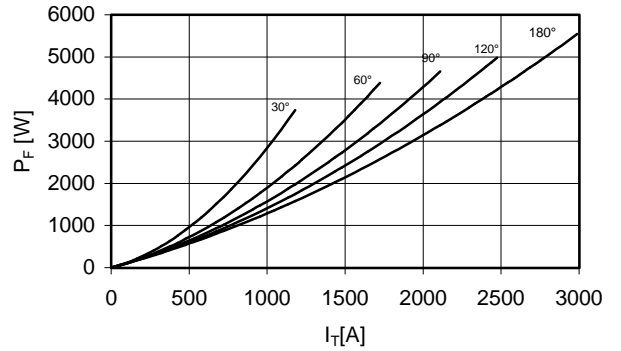
### THERMAL AND MECHANICAL CHARACTERISTICS

R <sub>th(j-c)</sub>	Thermal resistance (junction to case)	Double side cooled	0,016 °C/W
R <sub>th(c-h)</sub>	Thermal resistance (case to heatsink)	Double side cooled	0,001 °C/W
T <sub>jmax</sub>	Max operating junction temperature		150 °C
T <sub>stg</sub>	Storage temperature		-40 / 150 °C
F	Clamping force ± 10%		30 kN
	Mass		1400 g

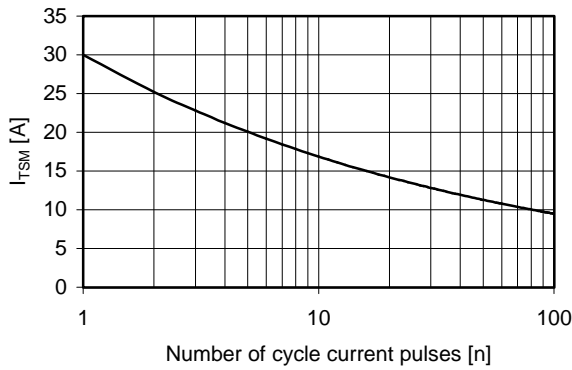
Current rating - sine wave



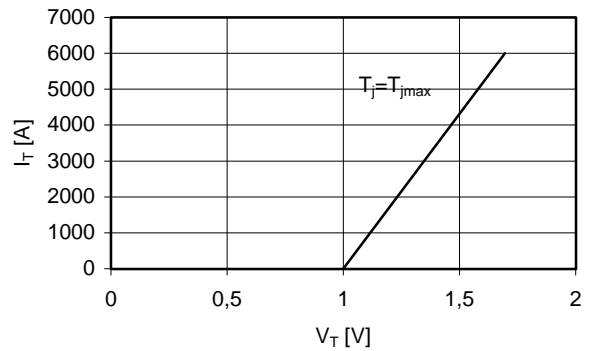
Power loss - sine wave



Maximum surge current d.s. cooled

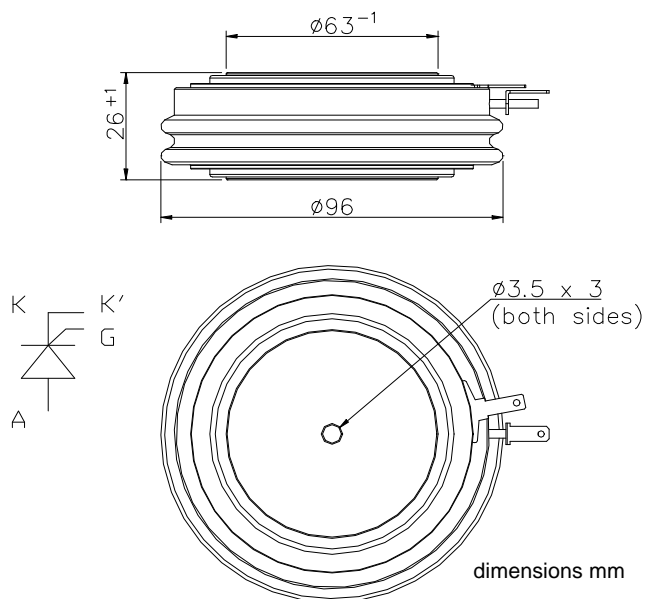
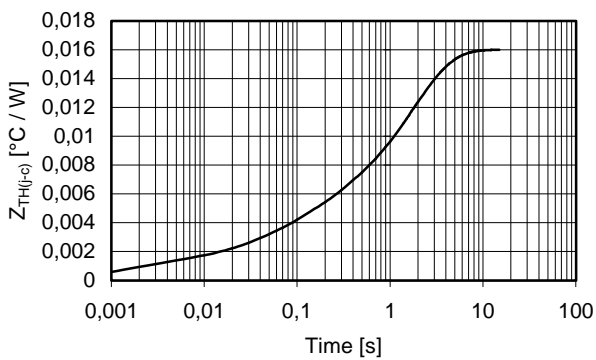


On-state voltage drop



Thermal impedance (j-c)

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In the interest of product improvement Green Power Solutions reserves the right to change any specification given in this data sheet without notice.